

# Direct Detection of the Dark Matter: Germanium detector Internal Amplification(GeIA) (Battle between “liquid Ne-77K” and “He-4K”)

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# Before the talk....

- Detector project – Cryogenic knowledge
- Filled with “Solid-State Physics”
- Try my best to explain the jargon well.

# Outline – Qualitative and Quantitative

- The principles of our experiment
- The issues we are engaging in
- The conclusion and prospect

WIMPs



Reach through region  
(Low E region)

Predicted by gravitation:

The velocity of the stars

→ Inconsistent with the existing law

→ Missing mass in our universe!

→ Weakly Interacting Massive Particles(WIMPs)

Avalanche region  
(High E region)

E-h generated

Mechanism:

(1)Excitation

(2)Ionization

electron



hole

Drifted in the crystal

Give out many electrons

$G(T, E \dots)$

Amplification

Purity: Ge

Impurity: Be, Al, Ga, (3A)-hole. "P-type detector"

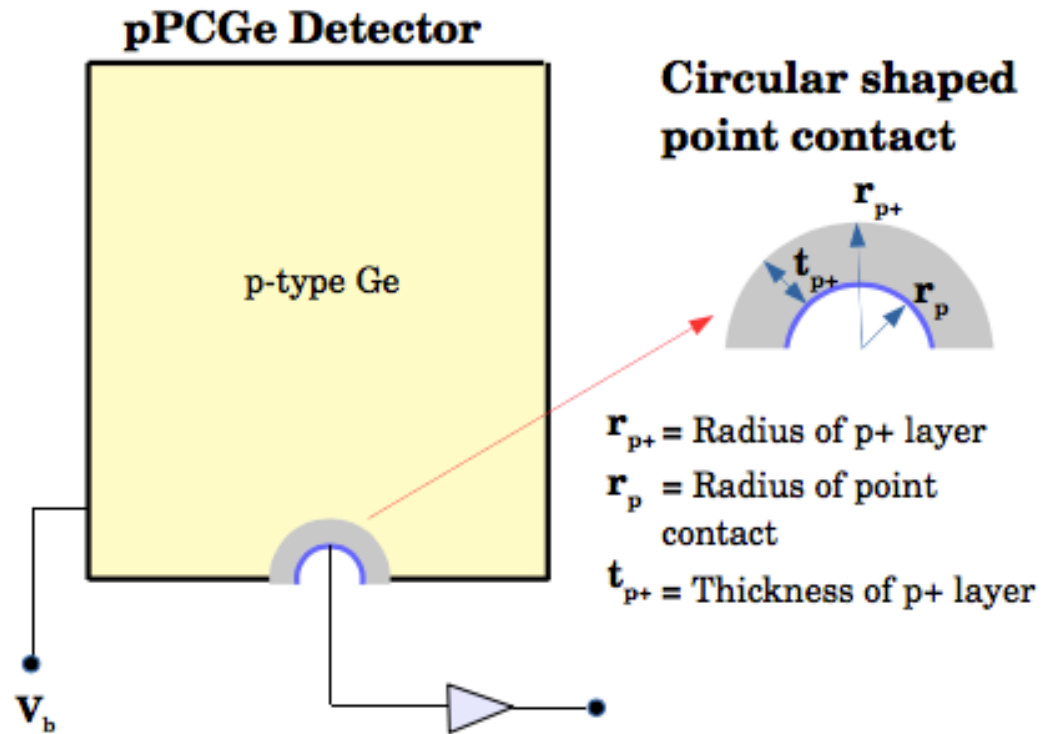
2019/8/21

GelA group

4

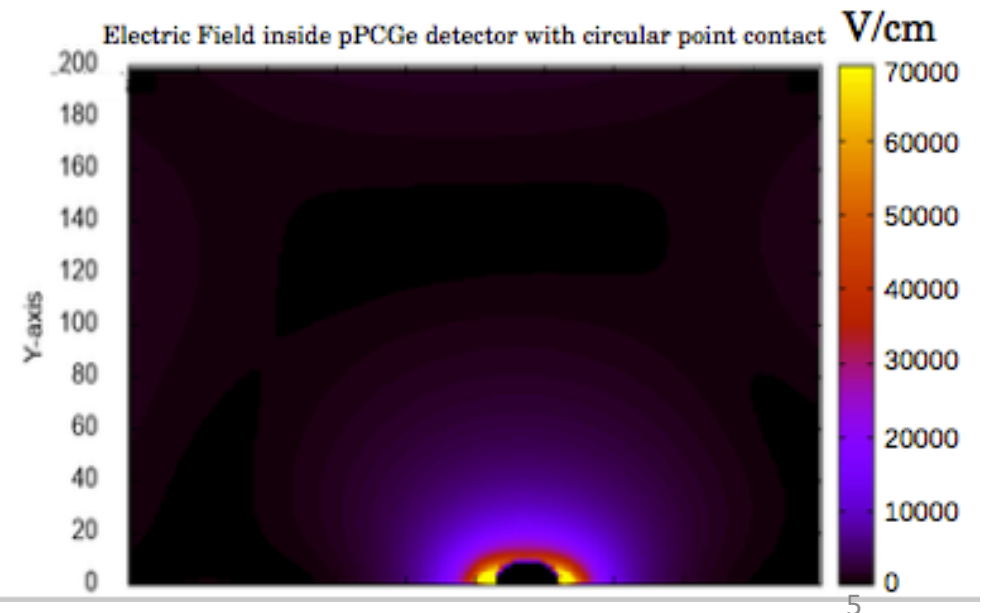
# Examples from other people

Shape of point contact and p+layer under Circular Geometry for pPCGe detector

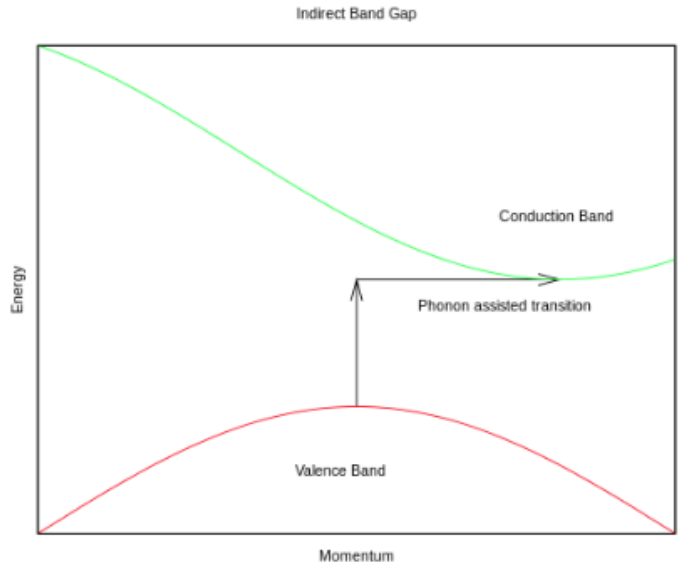


Electric Field

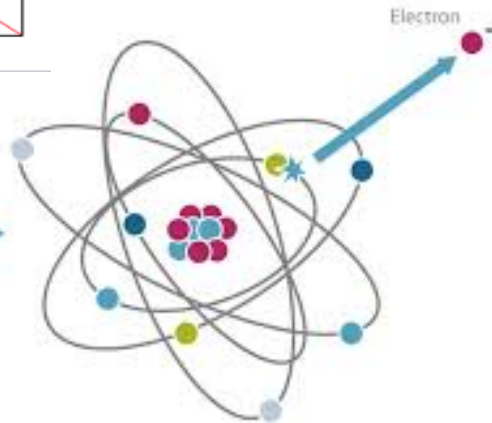
- Detector dimension : 1cm x 1cm
- Bias voltage : 3500 V
- Impurity concentration :  $5 \times 10^{10} \text{ cm}^{-3}$
- Radius of point contact  $r_p$  : 0.4997 mm
- Radius of p+ layer  $r_{p+}$  : 0.5 mm
- Thickness of p+ layer  $t_{p+}$  : 0.0003 mm (300 nm)



# Clarification(Solid-State Physics)



e-ion pair  
(e-h pair)



## The energy to produce E-h pair

	Excitation (Ionization)	Ionization
	-Ge	-Impurities
4K	3.3eV	0.01eV
77K	3.0eV	0.01eV

\*In our topic, we call them “Ionization” and “e-h pair” totally

➔ The one energy that can produce e-h pair

Issue?

I have the low background!

4K

I'm easy to be achieved!

77K

Versus

Liquid Helium

Liquid Nitrogen

(Beijing Tsing-Hua University)

Winner or Loser?

*Signal*  

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*Noise*

# Non-trivial issues

- Breakdown voltage
  - Leakage current
  - .....
  - Many issues at there!
- 
- At the beginning, we start at “Gain” without other noises!



# Gain factor

- How do we know about the gain?
- ➔ We need to know about the number of e-h pair we can produce!
- \*Ionization rate
- ➔ How many e-h pairs will be produced during the avalanche region?

# Parameter(1): Mean free path

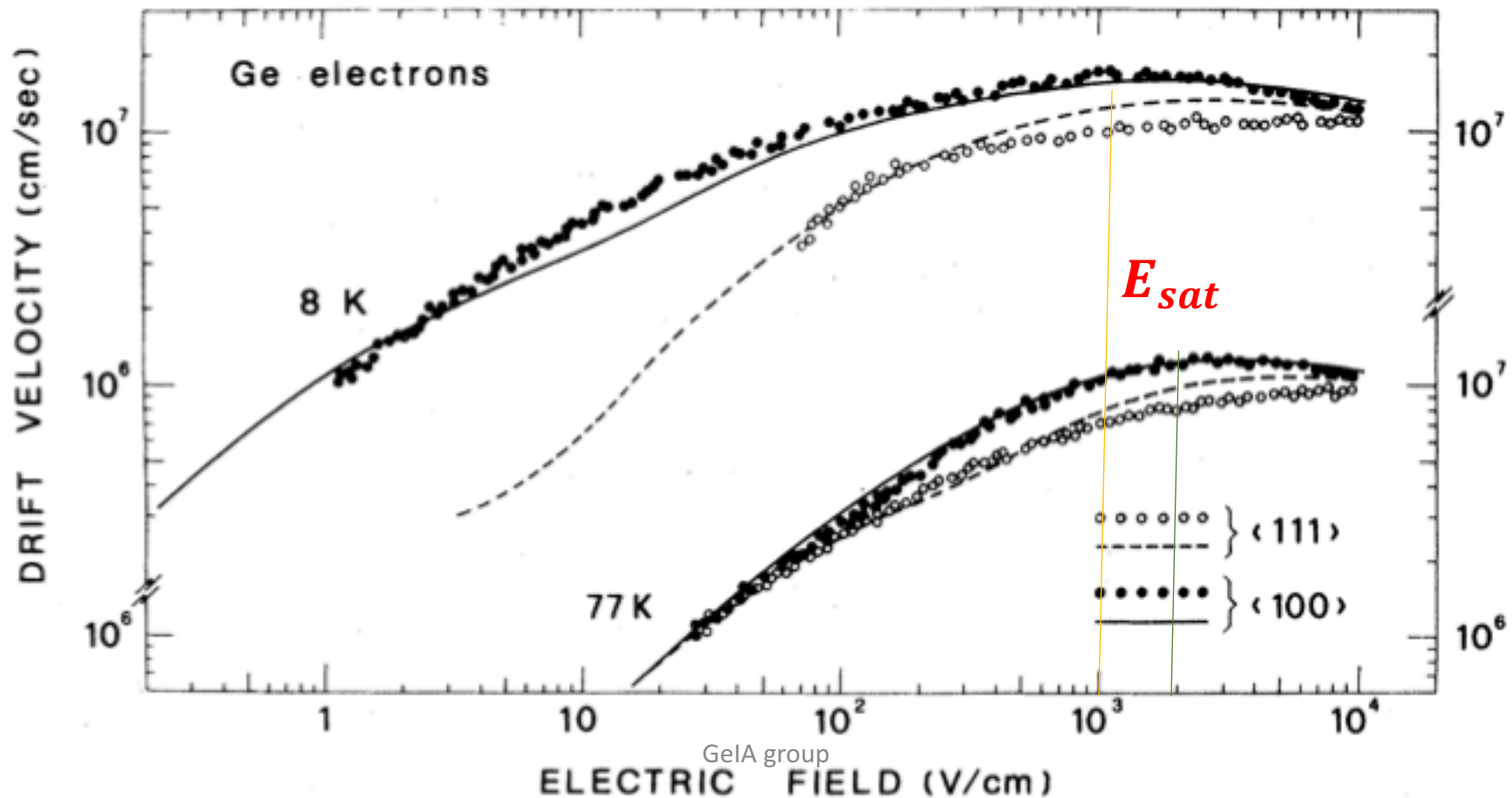
- \*Definition:
- How far the electron(hole) can run without colliding with others
- $(\text{Relaxation time}) * (\text{velocity})$

# Parameter(2): Relaxation time

- How long the electron(hole) can run without colliding with others
- Formula:  $\frac{\mu \times m^*}{e} = \tau$
- (1) $\mu$ (mobility) =  $\frac{v_d(1+\frac{E}{E_{sat}})}{E}$
- (2) $m^*$  (Effective mass): bounded electron ( $F=m^*a$ )
- ➔ Use effective mass to do the approximation
- ➔  $\text{electron}^* = 0.21^*(\text{free e- mass})$ ,  $\text{hole}^* = 0.12^*(\text{free e- mass})$
- (3) $e$ (Charge constant)

# Parameter(3): Velocity

PhysRevB.24.1014



# Parameter(4): Ionization rate

$$\alpha_s = \frac{a_s}{z} \exp\left(-\frac{b_s}{E(x)}\right) \quad \text{with } s = \{n, p\} \quad (20a)$$

and

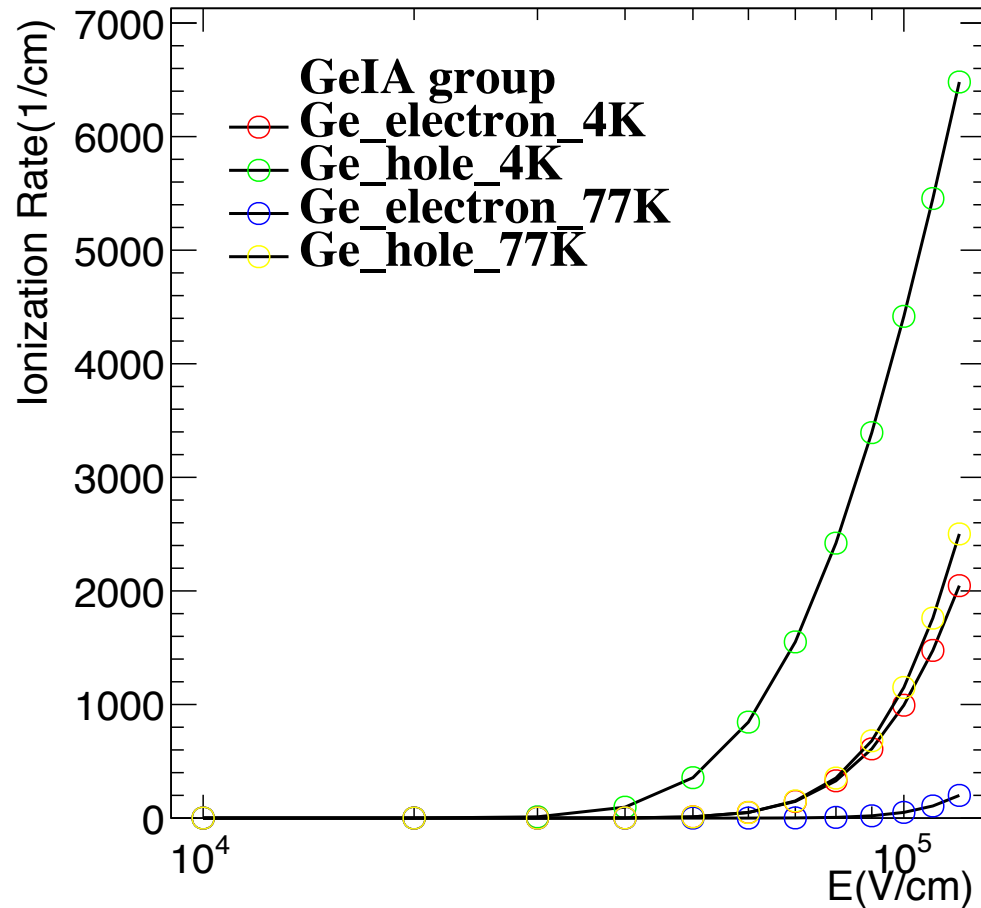
$$z(x) = 1 + \frac{b_n}{E(x)} \exp\left(-\frac{b_n}{E(x)}\right) + \frac{b_p}{E(x)} \exp\left(-\frac{b_p}{E(x)}\right) \quad (20b)$$

and

$$a_s = \gamma_s = \frac{1}{L_s} \quad \text{and} \quad b_s = \frac{U_c^s \gamma_s}{q} \quad (20c)$$

**Important point: (1) Mean free path (2) Ionization energy**

# Results – Ionization rate(1/cm)



How many e-h can be produced per centimeter?

(1) Hole's rate is bigger than electron's for both of the temperature

→ \*P-type detector (Benefit)

(2) At 4K, the rates of both electron and hole are bigger than 77K individually.

→ \*4K is the winner in this case.

(3) We need to use at least  $3 \times 10^4 \left(\frac{V}{cm}\right)$  to drive the Ge electron and hole if this case happens.

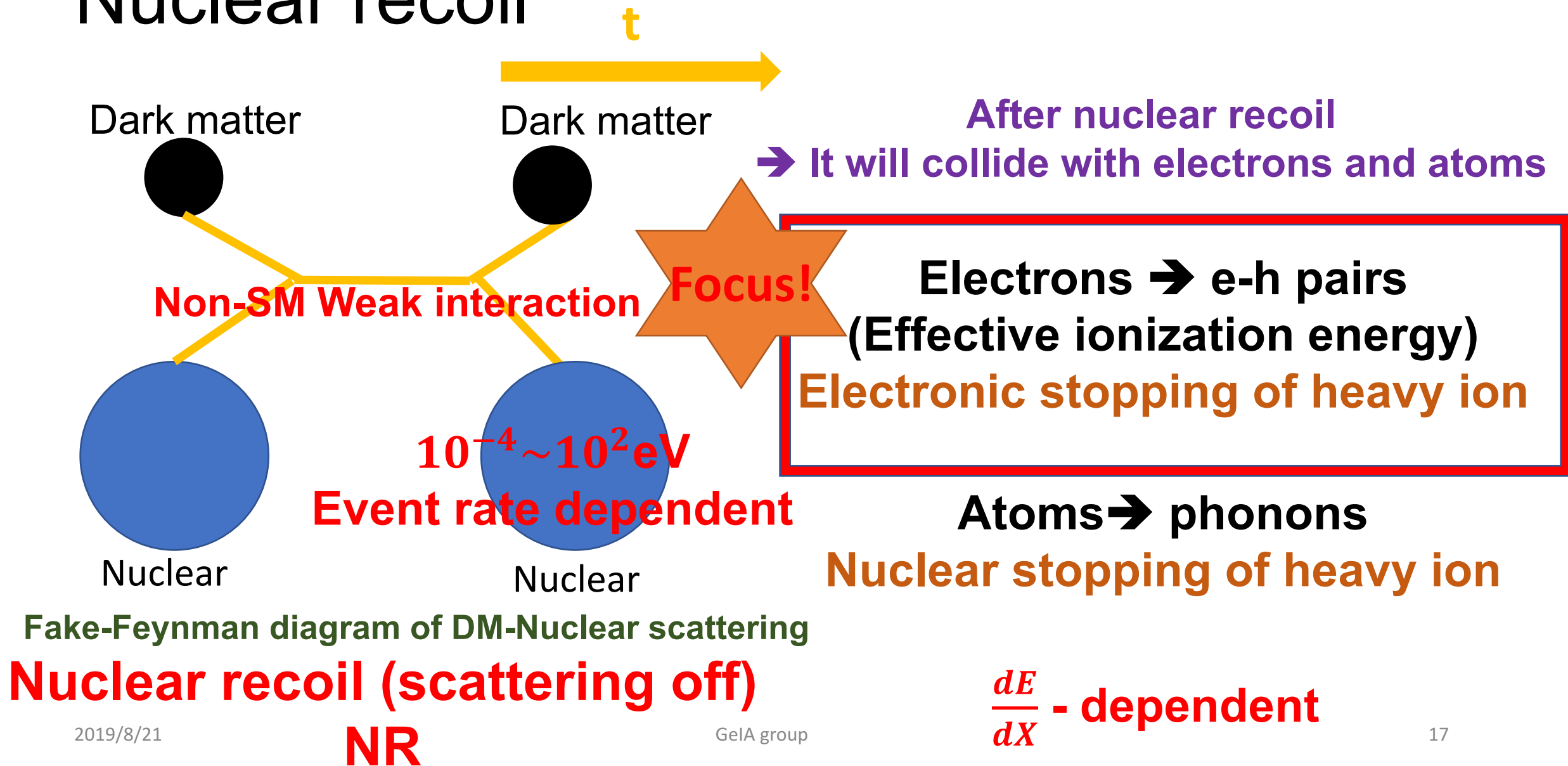
# Conclusion and Prospect

- For the ionization rate of the Ge electron and hole
- ➔ 4K is bigger than 77K for both of them.
- We need to use more than  $3 \times 10^4 (\frac{V}{cm})$  to drive the Ge electron and hole
- Next step:
- (1) Figure out the ionization rate of the impurities
- (2) Jump into the real point contact detector
- ➔ Use the real electric field in the detector to figure out the gain.

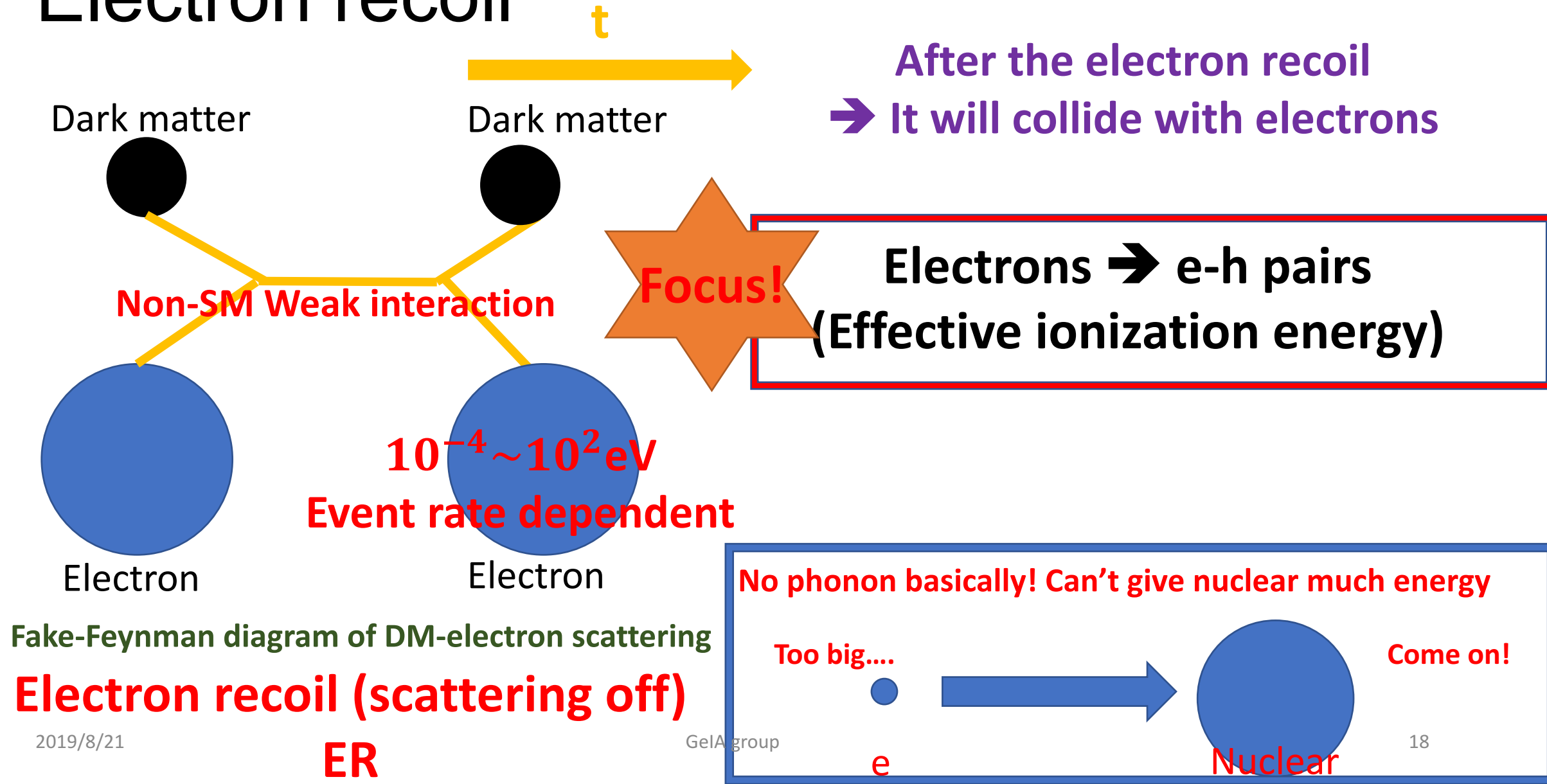
# BackUp

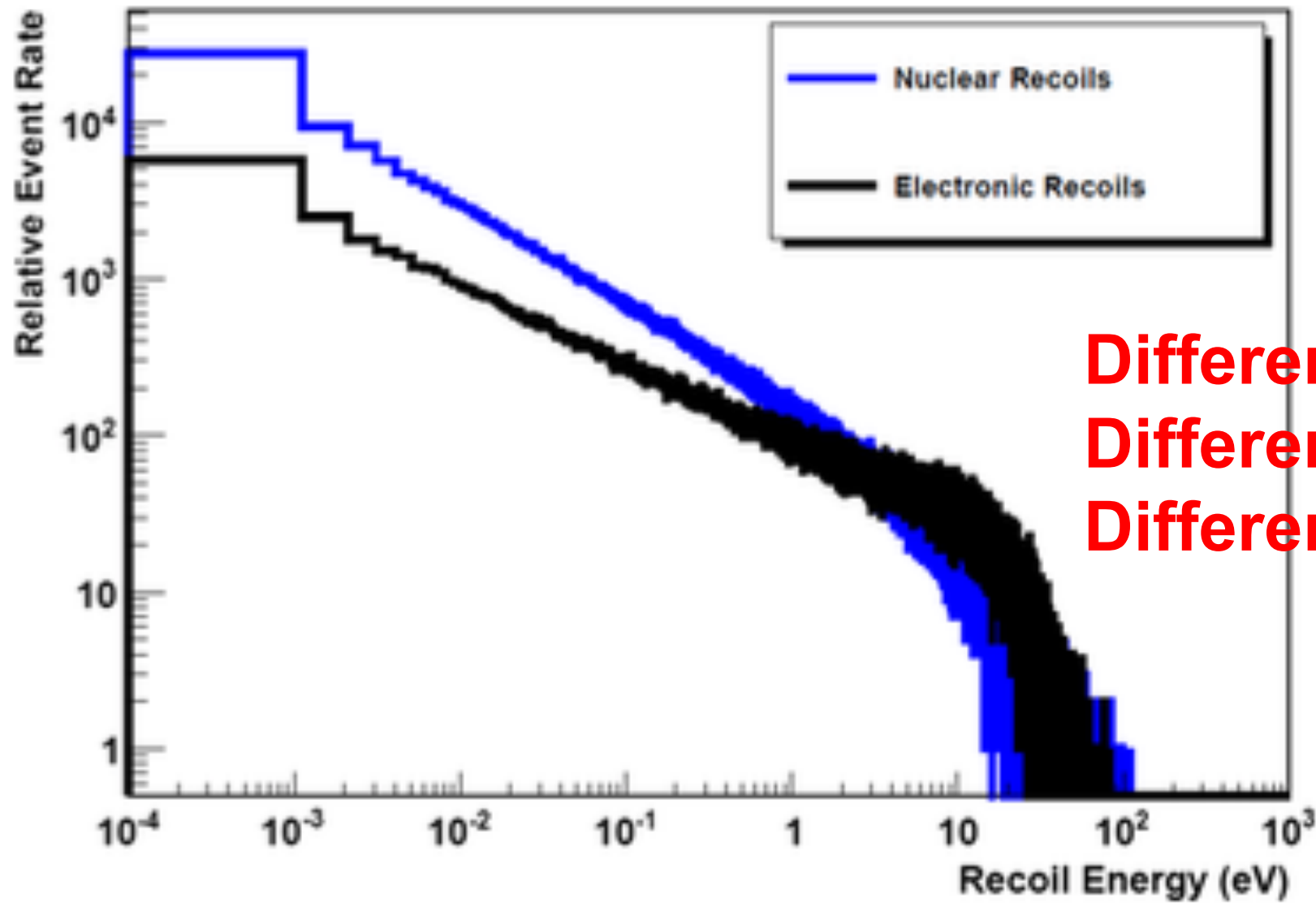


# Nuclear recoil



# Electron recoil





**Different DM Mass**  
**Different Recoil energy**  
**Different Relative event rate!**

GeV to MeV dark matters

**Fig. 1** The relative event rate as a function of recoil energy for DM with masses between 0.1 MeV/c<sup>2</sup> to 1 GeV/c<sup>2</sup>